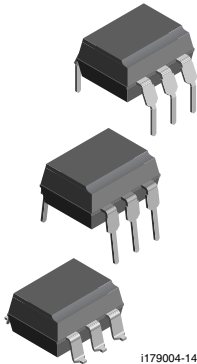
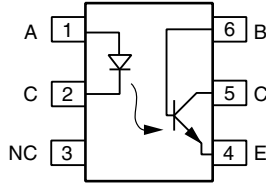


Optocoupler, Phototransistor Output, with Base Connection



i179004-14



DESCRIPTION

This datasheet presents five families of Vishay industry standard single channel phototransistor couplers. These families include the 4N35, 4N36, 4N37, 4N38 couplers.

Each optocoupler consists of gallium arsenide infrared LED and a silicon NPN phototransistor.

These couplers are Underwriters Laboratories (UL) listed to comply with a 5000 V_{RMS} isolation test voltage.

This isolation performance is accomplished through Vishay double molding isolation manufacturing process. Compliance to DIN EN 60747-5-5 partial discharge isolation specification is available for these families by ordering option 1.

These isolation processes and the Vishay ISO9001 quality program results in the highest isolation performance available for a commercial plastic phototransistor optocoupler.

The devices are available in lead formed configuration suitable for surface mounting and are available either on tape and reel, or in standard tube shipping containers.

Note

- For additional design information see application note 45 normalized curves

FEATURES

- Isolation test voltage 5000 V_{RMS}
- Interfaces with common logic families
- Input-output coupling capacitance < 0.5 pF
- Industry standard dual-in-line 6 pin package
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC


RoHS
COMPLIANT

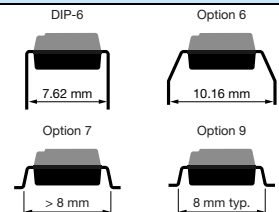
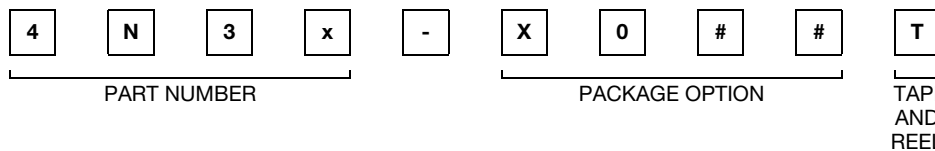
APPLICATIONS

- AC mains detection
- Reed relay driving
- Switch mode power supply feedback
- Telephone ring detection
- Logic ground isolation
- Logic coupling with high frequency noise rejection

AGENCY APPROVALS

- UL file no. E52744 (pending)
- cUL tested to CSA 22.2 bulletin 5A
- DIN EN 60747-5-2 (VDE 0884)/DIN EN 60747-5-5 (pending), available with option 1
- BSI: EN 60065, EN 60950-1
- FIMKO
- CQC

ORDERING INFORMATION



AGENCY CERTIFIED/PACKAGE	CTR (%)			
	10 mA		20 mA	
UL, cUL, BSI, FIMKO	≥ 100		≥ 20	
DIP-6	4N35-X000	4N36-X000	4N37-X000	4N38
DIP-6, 400 mil, option 6	4N35-X006	-	4N37-X006	-
SMD-6, option 7	4N35-X007T ⁽¹⁾	4N36-X007	4N37-X007	4N38-X007T ⁽¹⁾
SMD-6, option 9	4N35-X009T ⁽¹⁾	4N36-X009T ⁽¹⁾	4N37-X009	4N38-X009T
VDE, UL, cUL, BSI, FIMKO	≥ 100		≥ 20	
DIP-6	4N35-X001	-	4N37-X001	-
DIP-6, 400 mil, option 6	4N35-X016	-	-	-
SMD-6, option 7	4N35-X017T ⁽¹⁾	-	-	-
SMD-6, option 9	4N35-X019T	-	-	-

Notes

- Additional options may be possible, please contact sales office.
- ⁽¹⁾ Also available in tubes; do not put T on end.



ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
INPUT				
Reverse voltage		V _R	6	V
Forward current		I _F	60	mA
Surge current	t ≤ 10 μs	I _{FSM}	2.5	A
Power dissipation		P _{diss}	70	mW
OUTPUT				
Collector emitter breakdown voltage		V _{CEO}	70	V
Emitter base breakdown voltage		V _{EBO}	7	V
Collector current		I _C	50	mA
Collector peak current	t _p /T = 0.5, t _p ≤ 10 ms	I _{CM}	100	mA
Output power dissipation		P _{diss}	150	mW
COUPLER				
Isolation test voltage	t = 1 s	V _{ISO}	5000	V _{RMS}
Creepage distance			≥ 7	mm
Clearance distance			≥ 7	mm
Isolation thickness between emitter and detector			≥ 0.4	mm
Comparative tracking index	DIN IEC 112/VDE 0303, part 1		≥ 175	
Isolation resistance	V _{IO} = 500 V, T _{amb} = 25 °C	R _{IO}	≥ 10 ¹²	Ω
	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	≥ 10 ¹¹	Ω
Storage temperature		T _{stg}	- 55 to + 150	°C
Operating temperature		T _{amb}	- 55 to + 100	°C
Soldering temperature ⁽¹⁾	2 mm from case, ≤ 10 s	T _{sld}	260	°C

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.
- ⁽¹⁾ Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
INPUT							
Forward voltage ⁽¹⁾	I _F = 10 mA		V _F		1.2	1.5	V
	I _F = 10 mA, T _{amb} = - 55 °C		V _F	0.9	1.3	1.7	V
Reverse current ⁽¹⁾	V _R = 6 V		I _R		0.1	10	μA
Capacitance	V _R = 0 V, f = 1 MHz		C _O		25		pF
OUTPUT							
Collector emitter breakdown voltage ⁽¹⁾	I _C = 1 mA	4N35	BV _{CEO}	30			V
		4N36	BV _{CEO}	30			V
		4N37	BV _{CEO}	30			V
		4N38	BV _{CEO}	80			V
Emitter collector breakdown voltage ⁽¹⁾	I _E = 100 μA		BV _{ECO}	7			V
Collector base breakdown voltage ⁽¹⁾	I _C = 100 μA, I _B = 1 μA	4N35	BV _{CBO}	70			V
		4N36	BV _{CBO}	70			V
		4N37	BV _{CBO}	70			V
		4N38	BV _{CBO}	80			V

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
OUTPUT								
Collector emitter leakage current ⁽¹⁾	$V_{CE} = 10\text{ V}, I_F = 0$	4N35	I_{CEO}		5	50	nA	
		4N36	I_{CEO}		5	50	nA	
	$V_{CE} = 10\text{ V}, I_F = 0$	4N37	I_{CEO}		5	50	nA	
	$V_{CE} = 60\text{ V}, I_F = 0$	4N38	I_{CEO}			50	nA	
	$V_{CE} = 30\text{ V}, I_F = 0,$ $T_{amb} = 100\text{ }^{\circ}\text{C}$		4N35	I_{CEO}			500	μA
			4N36	I_{CEO}			500	μA
		4N37	I_{CEO}			500	μA	
	$V_{CE} = 60\text{ V}, I_F = 0,$ $T_{amb} = 100\text{ }^{\circ}\text{C}$	4N38	I_{CEO}		6		μA	
Collector emitter capacitance	$V_{CE} = 0$		C_{CE}		6		pF	
coupler								
Resistance, input output ⁽¹⁾	$V_{IO} = 500\text{ V}$		R_{IO}	10^{11}			Ω	
Capacitance, input output	$f = 1\text{ MHz}$		C_{IO}		0.5		pF	

Notes

- Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering evaluation. Typical values are for information only and are not part of the testing requirements.
- ⁽¹⁾ Indicates JEDEC registered value.

CURRENT TRANSFER RATIO ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)								
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT	
I_C/I_F ⁽¹⁾	$V_{CE} = 10\text{ V}, I_F = 10\text{ mA}$	4N35	CTR_{DC}	100			%	
		4N36	CTR_{DC}	100			%	
		4N37	CTR_{DC}	100			%	
	$V_{CE} = 10\text{ V}, I_F = 20\text{ mA}$	4N38	CTR_{DC}	20			%	
	$V_{CE} = 10\text{ V}, I_F = 10\text{ mA},$ $T_A = -55\text{ }^{\circ}\text{C to } +100\text{ }^{\circ}\text{C}$		4N35	CTR_{DC}	40	50		%
			4N36	CTR_{DC}	40	50		%
		4N37	CTR_{DC}	40	50		%	
		4N38	CTR_{DC}		30		%	

Note

- ⁽¹⁾ Indicates JEDEC registered values.

SWITCHING CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Turn-on time ⁽¹⁾	$V_{CC} = 5\text{ V}, I_C = 2\text{ mA}, R_L = 100\text{ }\Omega$	t_{on}		10		μs	
Turn-off time ⁽¹⁾	$V_{CC} = 5\text{ V}, I_C = 2\text{ mA}, R_L = 100\text{ }\Omega$	t_{off}		10		μs	

Note

- ⁽¹⁾ Indicates JEDEC registered values.



Fig. 1 - Test Circuit, Non-Saturated Operation



Fig. 2 - Switching Times

TYPICAL CHARACTERISTICS ($T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified)



Fig. 3 - Forward Voltage vs. Forward Current



Fig. 6 - Leakage Current vs. Ambient Temperature



Fig. 4 - Collector Current vs. Collector Emitter Voltage (NS)



Fig. 7 - Normalized CTR (NS) vs. Ambient Temperature



Fig. 5 - Collector Current vs. Collector Emitter Voltage (sat)



Fig. 8 - Normalized CTR (sat) vs. Ambient Temperature



Fig. 9 - Normalized CTR (NS) vs. Forward Current



Fig. 12 - CTR Frequency vs. Collector Current

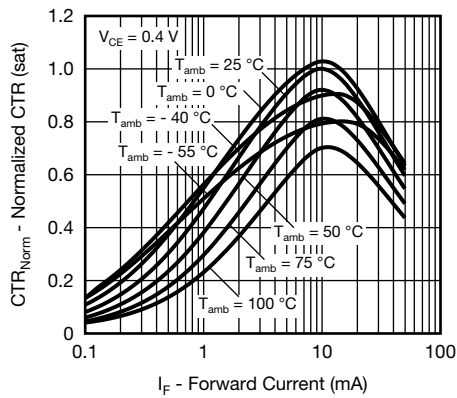


Fig. 10 - Normalized CTR (sat) vs. Forward Current

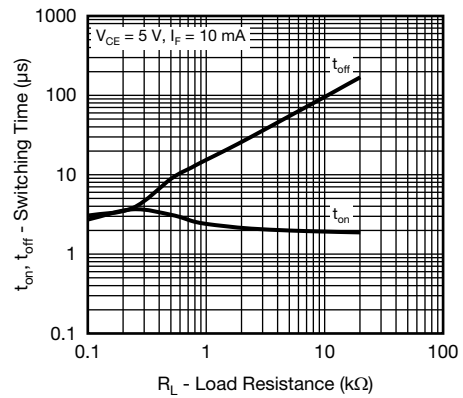


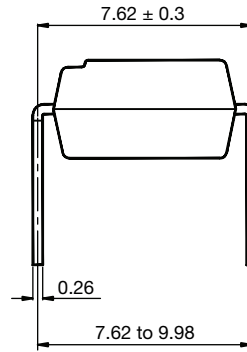
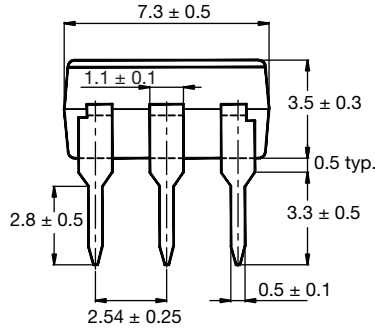
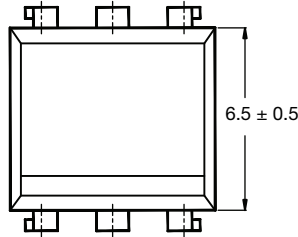
Fig. 13 - Switching Time vs. Load Resistance



Fig. 11 - CTR Frequency vs. Phase Angle



PACKAGE DIMENSIONS in millimeters

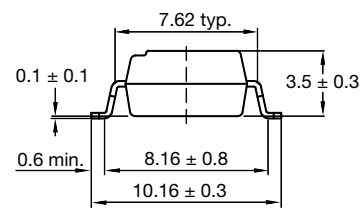
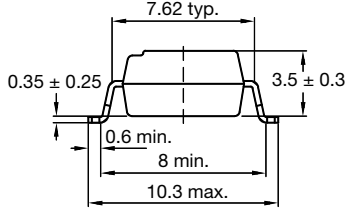
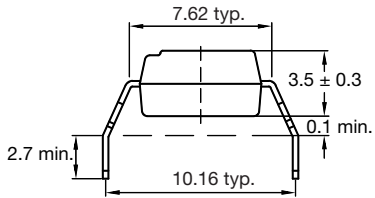


22530

Option 6

Option 7

Option 9



20802-34

PACKAGE MARKING



Notes

- VDE logo is only marked on option 1 parts. Option information is not marked on the part.
- Tape and reel suffix (T) is not part of the package marking.



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